

# HIGH-SPEED CMOS LOGIC HEX BUFFER/LINE DRIVER, THREE-STATE NON-INVERTING AND INVERTING

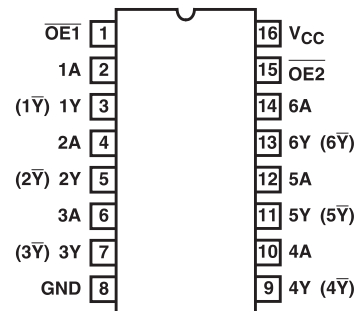
 Check for Samples: [CD74HC365-Q1](#), [CD74HC366-Q1](#), [CD74HCT365-Q1](#)

## FEATURES

- Qualified for Automotive Applications
- Buffered Inputs
- High Current Bus Driver Outputs
- Typical Propagation Delay  $t_{PLH}$ ,  $t_{PHL} = 8\text{ns}$  at  $V_{CC} = 5\text{V}$ ,  $C_L = 15\text{pF}$ ,  $T_A = 25^\circ\text{C}$
- Fanout (Over Temperature Range)
  - Standard Outputs . . . . . 10 LSTTL Loads
  - Bus Driver Outputs . . . . . 15 LSTTL Loads
- Wide Operating Temperature Range . . .  $-40^\circ\text{C}$  to  $125^\circ\text{C}$
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity:  $N_{IL} = 30\%$ ,  $N_{IH} = 30\%$  of  $V_{CC}$  at  $V_{CC} = 5\text{V}$

## HCT Types

- 4.5V to 5.5V Operation
- Direct LSTTL Input Logic Compatibility,  $V_{IL} = 0.8\text{V}$  (Max),  $V_{IH} = 2\text{V}$  (Min)
- CMOS Input Compatibility,  $I_I \leq 1\mu\text{A}$  at  $V_{OL}$ ,  $V_{OH}$

**D PACKAGE  
(TOP VIEW)**


## DESCRIPTION

The CD74HC365-Q1, CD74HC366-Q1, and CD74HCT365-Q1 silicon gate CMOS three state buffers are general purpose high-speed non-inverting and inverting buffers. They have high drive current outputs which enable high speed operation even when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuitry, yet have speeds comparable to low power Schottky TTL circuits. Both circuits are capable of driving up to 15 low power Schottky inputs.

The CD74HC365-Q1 and CD74HCT365-Q1 are non-inverting buffers, whereas the CD74HC366-Q1 is an inverting buffer. These devices have two three-state control inputs ( $\overline{OE1}$  and  $\overline{OE2}$ ) which are NORed together to control all six gates.

The 'HCT365-Q1 logic families are speed, function and pin compatible with the standard LS logic family.

## ORDERING INFORMATION<sup>(1)</sup>

$T_A$	PACKAGE <sup>(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
$-40^\circ\text{C}$ to $125^\circ\text{C}$	SOIC – D	Reel of 2500	CD74HC366QDRQ1	HC366Q
			CD74HC365QDRQ1	Product Preview
			CD74HCT365QDRQ1	Product Preview

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at [www.ti.com](http://www.ti.com).

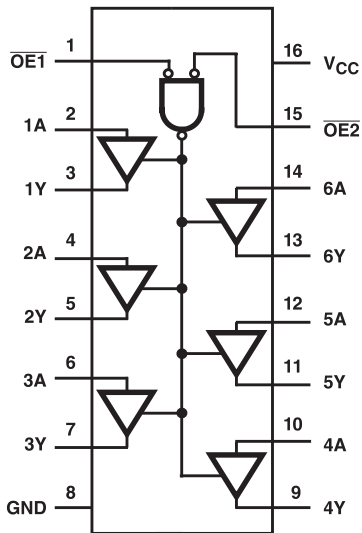
(2) Package drawings, thermal data, and symbolization are available at [www.ti.com/packaging](http://www.ti.com/packaging).



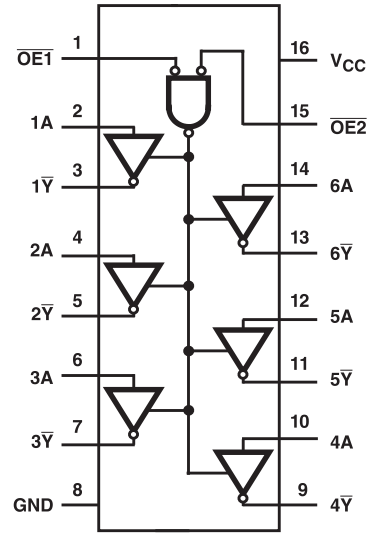
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FUNCTIONAL DIAGRAMS

CD74HC365-Q1, CD74HCT365-Q1



CD74HC366-Q1

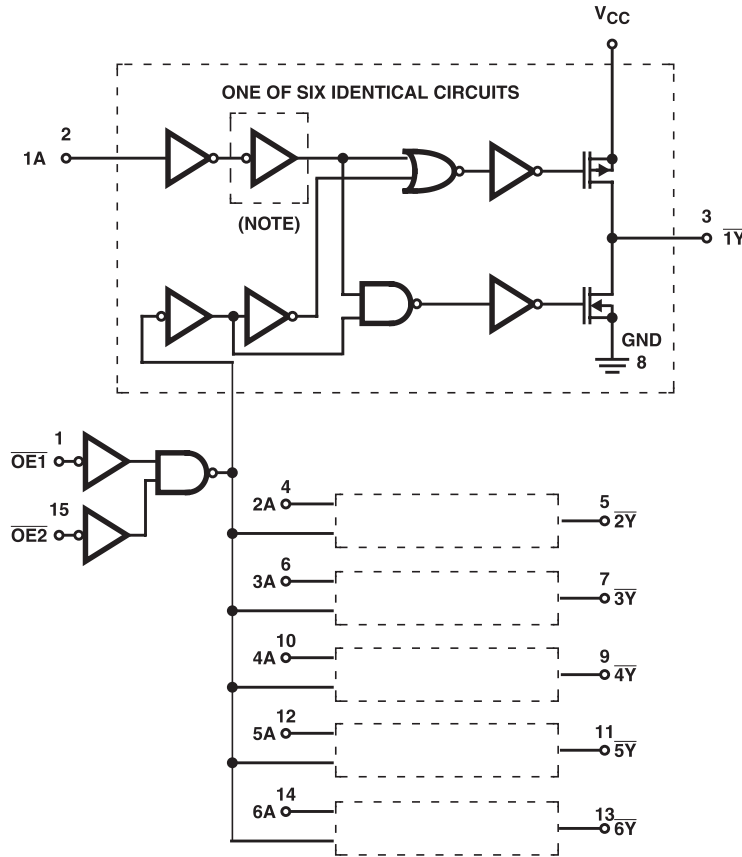


TRUTH TABLE<sup>(1)</sup>

INPUTS			OUTPUTS (Y)	
OE1	OE2	A	HC/HCT365	HC366
L	L	L	L	H
L	L	H	H	L
X	H	X	Z	Z
H	X	X	Z	Z

- (1) H = High Voltage Level
- L = Low Voltage Level
- X = Don't Care
- Z = High Impedance (OFF) State

LOGIC DIAGRAM



NOTE: Inverter not included in CD74HC365-Q1, CD74HCT365-Q1

**Figure 1. LOGIC DIAGRAM FOR THE HC/HCT365 AND HC366**  
(outputs for HC/HCT365 are complements of those shown, i.e., 1Y, 2Y, etc.)

### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

PARAMETER		CONDITIONS	VALUE
V <sub>CC</sub>	DC supply voltage		-0.5V to +7V
I <sub>IK</sub>	DC input diode current,	V <sub>I</sub> < -0.5V or V <sub>I</sub> > V <sub>CC</sub> + 0.5V	±20mA
I <sub>OK</sub>	DC output diode current	V <sub>O</sub> < -0.5V or V <sub>O</sub> > V <sub>CC</sub> + 0.5V	±20mA
I <sub>O</sub>	DC drain current per output	V <sub>O</sub> > -0.5V or V <sub>O</sub> < V <sub>CC</sub> + 0.5V	±35mA
	DC output source or sink current per output pin		±25mA
I <sub>CC</sub>	DC V <sub>CC</sub> or ground current		±50mA
ESD	Electrostatic discharge	Human-Body Model	1.5kV
		Machine Model	200V
		Field-Induced-Charged Device Model	250V
Latch up			Class I

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### THERMAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

PARAMETER		MIN	MAX	UNIT
θ <sub>JA</sub>	Thermal resistance (typical) <sup>(1)</sup>		73	°C/W
J <sub>T</sub>	Maximum junction temperature		150	°C
T <sub>stg</sub>	Maximum storage temperature range	-65	150	°C
	Maximum lead temperature (soldering 10s)		300	°C

(1) The package thermal impedance is calculated in accordance with JESD 51-7.

### RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	HC Types	2	6
		HCT Types	4.5	5.5
V <sub>I</sub>	DC Input voltage	0	V <sub>CC</sub>	V
V <sub>O</sub>	DC Output voltage	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating free-air temperature	-40	125	°C
	Input Rise and Fall Time	2 V	1000	ns
		4.5 V	500	
		6 V	400	

**ELECTRICAL CHARACTERISTICS**

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		V <sub>CC</sub> (V)	25°C			-40°C TO 125°C		UNITS	
		V <sub>I</sub> (V)	I <sub>O</sub> (mA)		MIN	TYP	MAX	MIN	MAX		
<b>HC Types</b>											
V <sub>IH</sub>	High-level input voltage			2	1.5	-	-	1.5	-	V	
				4.5	3.15	-	-	3.15	-		
				6	4.2	-	-	4.2	-		
V <sub>IL</sub>	Low-level input voltage			2	-	-	0.5	-	0.5	V	
				4.5	-	-	1.35	-	1.35		
				6	-	-	1.8	-	1.8		
V <sub>OH</sub>	High-level output voltage loads	CMOS	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	2	1.9	-	-	1.9	-	V
				4.5	4.4	-	-	4.4	-		
		TTL		-6	4.5	3.98	-	-	3.7	-	
				-7.8	6	5.48	-	-	5.2	-	
V <sub>OL</sub>	Low-level output voltage loads	CMOS	V <sub>IH</sub> or V <sub>IL</sub>	0.02	2	-	-	0.1	-	0.1	V
				4.5	-	-	0.1	-	0.1		
		TTL		6	4.5	-	-	0.26	-	0.4	
				7.8	6	-	-	0.26	-	0.4	
I <sub>I</sub>	Input leakage current	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	μA	
I <sub>CC</sub>	Quiescent device current	V <sub>CC</sub> or GND	0	6	-	-	8	-	160	μA	
I <sub>OZ</sub>	Three-state leakage current	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	6	-	-	±0.5	-	±10	μA	
<b>HCT Types</b>											
V <sub>IH</sub>	High-level input voltage	-	-	4.5 to 5.5	2	-	-	2	-	V	
V <sub>IL</sub>	Low-level input voltage	-	-	4.5 to 5.5	-	-	0.8	-	0.8	V	
V <sub>OH</sub>	High-level output voltage loads	CMOS	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	V
		TTL		-4	4.5	3.98	-	-	3.7	-	
V <sub>OL</sub>	Low-level output voltage loads	CMOS	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	V
		TTL		4	4.5	-	-	0.26	-	0.4	
I <sub>I</sub>	Input leakage current	V <sub>CC</sub> or GND	-	5.5	-	-	±0.1	-	±1	μA	
I <sub>CC</sub>	Quiescent device current	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	160	μA	
ΔI <sub>CC</sub>	Additional quiescent device current per input pin: 1 unit load <sup>(1)</sup>	V <sub>CC</sub> - 2.1	-	4.5 to 5.5	-	100	360	-	490	μA	
I <sub>OZ</sub>	Three-state leakage current	V <sub>IH</sub> or V <sub>IL</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5	-	-	±0.5	-	±10	μA	

 (1) For dual-supply systems theoretical worst case (V<sub>I</sub> = 2.4V, V<sub>CC</sub> = 5.5V) specification is 1.8mA.

**HCT Input Loading**

INPUT	UNIT LOADS
$\overline{OE1}$	0.6
All Others	0.55

**SWITCHING CHARACTERISTICS**

Input  $t_r, t_f = 6\text{ns}$

PARAMETER		TEST CONDITIONS	V <sub>CC</sub> (V)	25°C		-40°C TO 125°C	UNITS
				TYP	MAX	MAX	
<b>HC Types</b>							
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation delay, data to outputs	HC365	C <sub>L</sub> = 50pF	2	-	110	165
				4.5	-	22	33
				6	-	19	28
		HC366	C <sub>L</sub> = 15pF	5	9	-	-
				C <sub>L</sub> = 50pF	2	-	150
			4.5		-	31	45
			6		-	26	38
			C <sub>L</sub> = 15pF	5	12	-	-
t <sub>TLH</sub> , t <sub>THL</sub>	Output transition time	C <sub>L</sub> = 50pF	2	-	60	90	
			4.5	-	12	18	
			6	-	10	15	
C <sub>I</sub>	Input capacitance	-	-	-	10	10	pF
C <sub>O</sub>	Three-state output capacitance	-	-	-	20	20	pF
C <sub>PD</sub>	Power dissipation capacitance <sup>(1)(2)</sup>	-	5	40	-	-	pF
<b>HCT Types</b>							
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation delay, data to outputs	HCT365	C <sub>L</sub> = 50pF	4.5	-	25	38
			CL = 15pF	5	9	-	-
		HCT366	C <sub>L</sub> = 50pF	4.5	-	27	41
			CL = 15pF	5	11	-	-
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation delay, output enable and disable to outputs		C <sub>L</sub> = 50pF	4.5	-	35	53
			C <sub>L</sub> = 15pF	5	14	-	-
t <sub>TLH</sub> , t <sub>THL</sub>	Output transition time	C <sub>L</sub> = 50pF	4.5	-	12	18	ns
C <sub>I</sub>	Input capacitance	-	-	-	10	10	pF
C <sub>O</sub>	Three-state output capacitance	-	-	-	20	20	pF
C <sub>PD</sub>	Power dissipation capacitance <sup>(1)(2)</sup>	-	5	42	-	-	pF

(1) C<sub>PD</sub> is used to determine the dynamic power consumption, per inverter.

(2) P<sub>D</sub> = V<sub>CC2</sub> × f<sub>i</sub> (C<sub>PD</sub> + C<sub>L</sub>), where f<sub>i</sub> = input frequency, C<sub>L</sub> = output load capacitance, V<sub>CC</sub> = supply voltage

TEST CIRCUIT AND WAVEFORMS

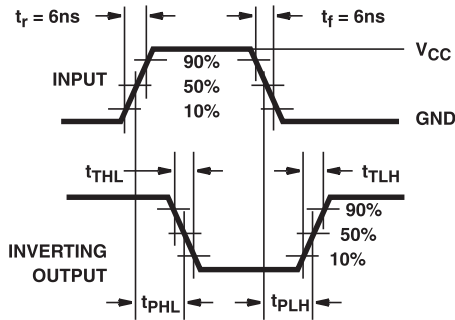


Figure 2. HC and HCU Transition Times and Propagation Delay Times, Combination Logic

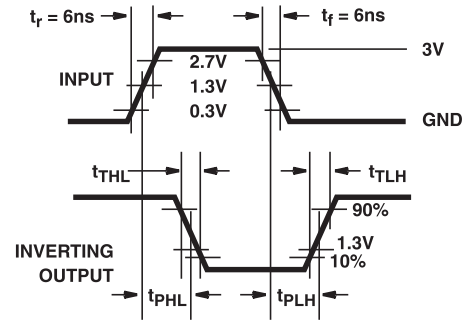


Figure 3. HCT Transition Times and Propagation Delay Times, Combination Logic

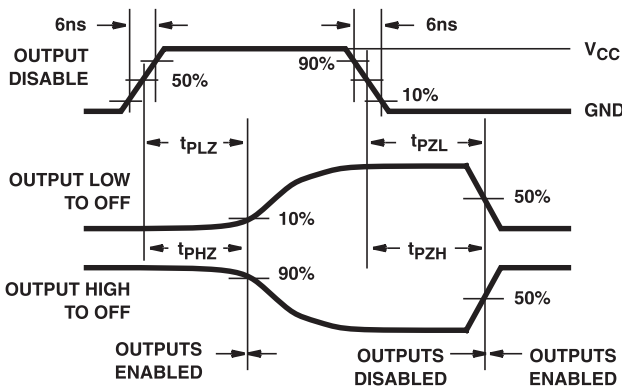


Figure 4. HC Three-State Propagation Delay Waveform

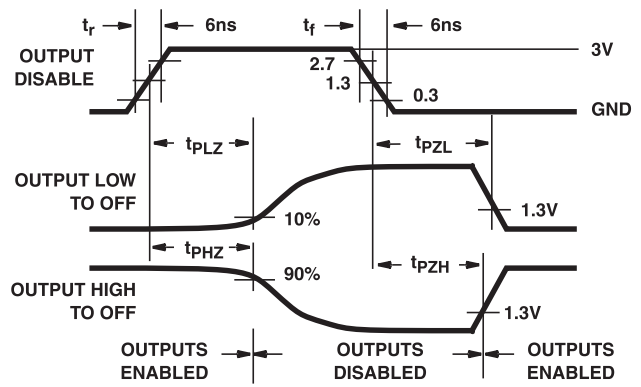
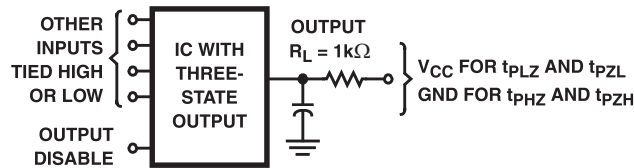


Figure 5. HCT Three-State Propagation Delay Waveform



NOTE: Open drain waveforms  $t_{PLZ}$  and  $t_{PZL}$  are the same as those for three-state shown on the left. The test circuit is Output  $R_L = 1k\Omega$  to  $V_{CC}$ .  $C_L = 50pF$ .

Figure 6. HC and HCT Three-State Propagation Delay Test Circuit

**PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
CD74HC366QDRQ1	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	<a href="#">Purchase Samples</a>

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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**OTHER QUALIFIED VERSIONS OF CD74HC366-Q1 :**

● Catalog: [CD74HC366](#)

● Military: [CD54HC366](#)

NOTE: Qualified Version Definitions:



- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



4040047-6/M 06/11

- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  -  Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  -  Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AC.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
  - This drawing is subject to change without notice.
  - Publication IPC-7351 is recommended for alternate designs.
  - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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